

## IRLL024ZTRPBF-VB Datasheet

## N-Channel 60-V (D-S) MOSFET

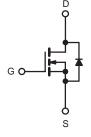
PRODU	CT SUMMARY	
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
60	0.028 at V <sub>GS</sub> = 10 V	7.0
00	0.033 at V <sub>GS</sub> = 4.5 V	5.6

#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Definition
- Trench Power MOSFETs
- 175 °C Maximum Junction Temperature
- Compliant to RoHS Directive 2002/95/EC



Available



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	$T_A = 25 \ ^{\circ}C$ , unles	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	6	60	V
Gate-Source Voltage		V <sub>GS</sub>	±	20	v
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	7.0	6.0	
Continuous Drain Current $(1) = 175$ C)	T <sub>A</sub> = 70 °C	טי	6.1	5.0	А
Pulsed Drain Current		I <sub>DM</sub>	4	0	~
Avalanche Current		I <sub>AS</sub>	1	5	
Single Pulse Avalanche Energy		E <sub>AS</sub>	1	1	mJ
Movimum Dower Dissignational	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.3	1.7	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	• 0	2.3	1.2	vv
Operating Junction and Storage Temperature Ran	nge	T <sub>J</sub> , T <sub>stg</sub>	- 55 t	o 175	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mauianum lunation to Ambient a	t ≤ 10 s	R <sub>thJA</sub>	36	45	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		75	90	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	20	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

SOT-223

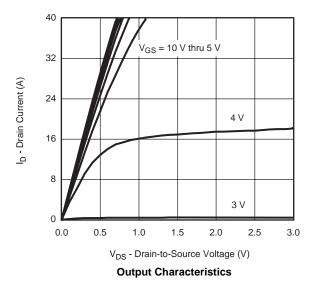
<b>SPECIFICATIONS</b> $T_J = 25 \ ^{\circ}C$	, unless ot	therwise noted					
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	60			V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1		3	v	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA	
Zero Gale voltage Drain Current	USS	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$			20	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	40			А	
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6.0 \text{ A}$		0.028		Ω	
	P	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6.0 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		0.032			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 6.0 A, T <sub>J</sub> = 175 °C		0.040			
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 5.1 A		0.033			
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 6.0 A		25		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 1.7 A, V <sub>GS</sub> = 0 V		0.8	1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg			18	27		
Gate-Source Charge	$Q_{gs}$ V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 6.0 A			3.4		nC	
Gate-Drain Charge	Q <sub>gd</sub>			5.3			
Gate Resistance	Rg	V <sub>GS</sub> = 0.1 V, f = 5 MHz	0.5	1.4	2.4	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			10	20		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 30 $\Omega$		10	20		
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ 1 A, $\text{V}_\text{GEN}$ = 10 V, $\text{R}_\text{g}$ = 6 $\Omega$		25	50	ns	
Fall Time	t <sub>f</sub>			12	24		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.7 A, dl/dt = 100 A/µs		50	80		

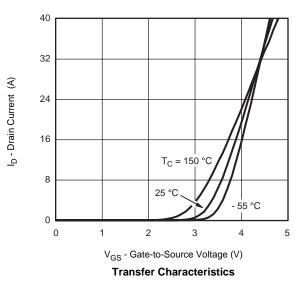
Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

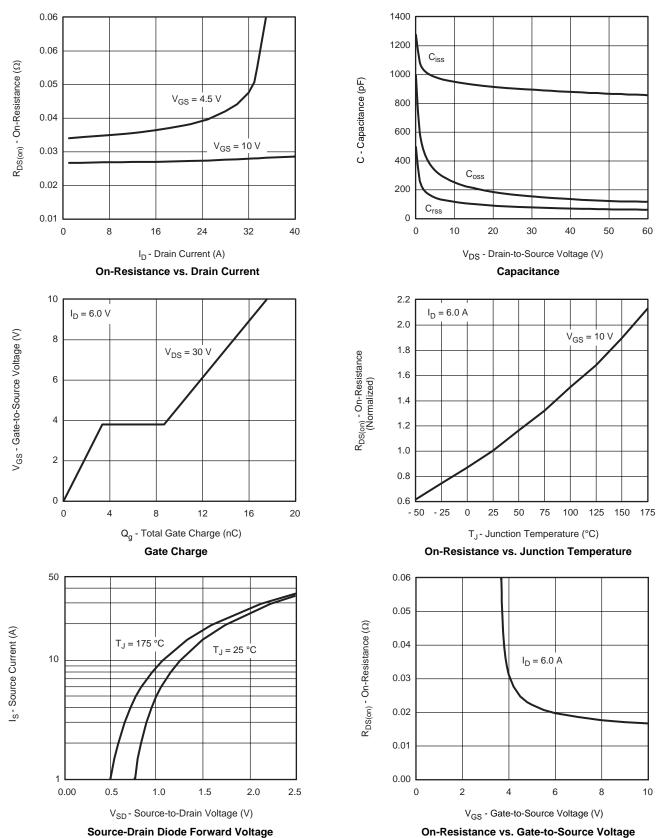




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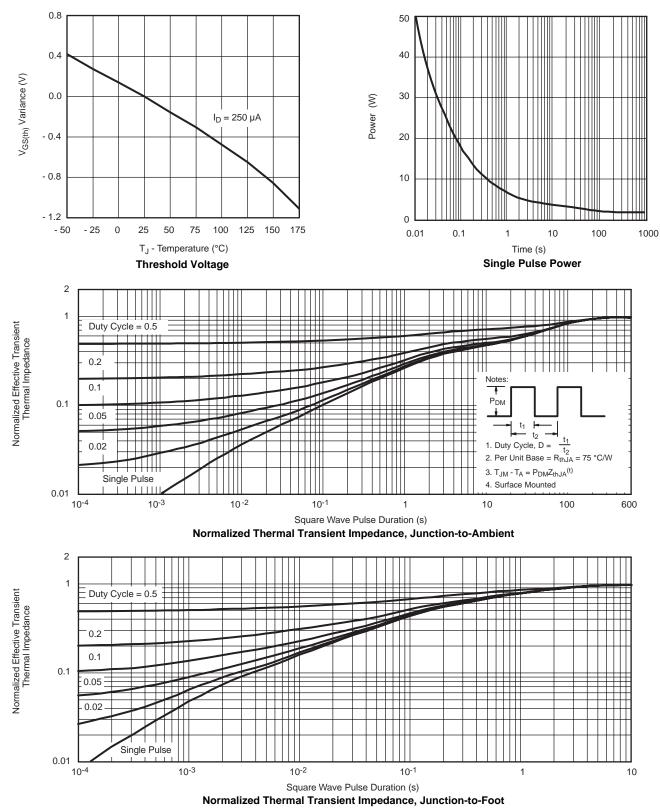
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



服务热线:400-655-8788

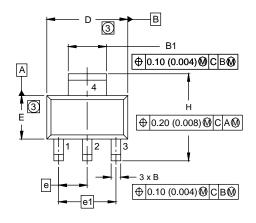


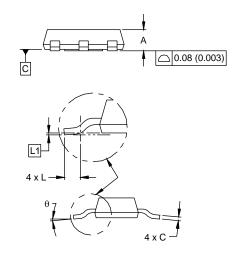
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





### SOT-223 (HIGH VOLTAGE)





DIM.	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
А	1.55	1.80	0.061	0.071	
В	0.65	0.85	0.026	0.033	
B1	2.95	3.15	0.116	0.124	
С	0.25	0.35	0.010	0.014	
D	6.30	6.70	0.248	0.264	
E	3.30	3.70	0.130	0.146	
е	2.30 BSC		0.0905 BSC		
e1	4.60 BSC		0.181 BSC		
Н	6.71	7.29	0.264	0.287	
L	0.91	-	0.036	-	
L1	0.061 BSC		0.002	4 BSC	
θ	-	10'	-	10'	

#### Notes

1. Dimensioning and tolerancing per ASME Y14.5M-1994.

2. Dimensions are shown in millimeters (inches).

3. Dimension do not include mold flash.

4. Outline conforms to JEDEC outline TO-261AA.



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